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4.2 Electronic and Structural Properties of Single Crystals4.2.1 Intrinsic Transport Properties; 4.2.2 Crystal Dimensionality; 4.3 Crystallization Techniques; 4.3.1 Growth from Vapor Phase; 4.3.2 Growth from Solution; 4.4 Single-Crystal Flexible Electronic Devices; 4.4.1 Fundamental Mechanics for Flexible Electronics; 4.4.2 Mechanical Versatility of Organic Single Crystals; 4.4.3 Importance of Mechanical Properties Knowledge; 4.4.4 The Elastic Constants of Rubrene Single Crystals; 4.5 Strategies for Flexible Organic Single-Crystal Device Fabrication
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Sommario/riassunto

From materials to applications, this ready reference covers the entire value chain from fundamentals via processing right up to devices, presenting different approaches to large-area electronics, thus enabling readers to compare materials, properties and performance. Divided into two parts, the first focuses on the materials used for the electronic functionality, covering organic and inorganic semiconductors, including vacuum and solution-processed metal-oxide semiconductors, nanomembranes and nanocrystals, as well as conductors and insulators. The second part reviews the devices and applicatio